

Product Summary

BV _{DSS}	R _{DS(on)} max	I _D T _A = +25°C
30V	30mΩ @ V _{GS} = 10V	6A
	40mΩ @ V _{GS} = 4.5V	4A

Description and Applications

This new generation small-signal enhancement mode MOSFET features low on-resistance and fast switching, making it ideal for high-efficiency power management applications.

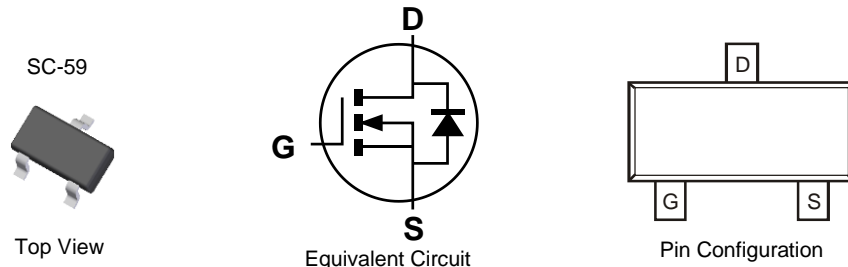
- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

Features

- Low Gate Charge
- Low R_{DS(ON)}
- Low Input/Output Leakage
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP (Note 4)**

Mechanical Data

- Case: SC-59
- Case Material - Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish - Matte Tin Annealed over Copper Leadframe;
- Solderable per MIL-STD-202, Method 208 Ⓔ3
- Weight: 0.014 grams (Approximate)

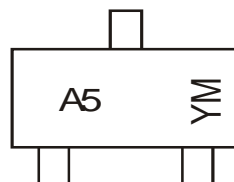


Ordering Information (Note 5)

Part Number	Case	Packaging
DMN3033LSNQ-7	SC-59	3,000/Tape & Reel
DMN3033LSNQ-13	SC-59	10,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



A5 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: U = 2007)
 M = Month (ex: 9 = September)

Date Code Key

Year	2007	...	2015	2016	2017	2018	2019	2020	2021	2022
Code	U	...	C	D	E	F	G	H	I	J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	±20	V
Drain Current (Note 6) Continuous	I _D	6	A
		5	
Pulsed Drain Current (Note 7)	I _{DM}	24	A
Body-Diode Continuous Current (Note 6)	I _S	2.25	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P _D	1.4	W
Thermal Resistance, Junction to Ambient (Note 6) t ≤ 10s	R _{θJA}	90	°C /W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 6. Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width t ≤ 10s.
7. Repetitive Rating, pulse width limited by junction temperature.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
STATIC PARAMETERS						
Drain-Source Breakdown Voltage	BV _{DSS}	30	—	—	V	I _D = 250μA, V _{GS} = 0V
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	μA	V _{DS} = 30V, V _{GS} = 0V
				5		
Gate-Body Leakage Current	I _{GSS}	—	—	±100	nA	V _{DS} = 0V, V _{GS} = ±20V
Gate Threshold Voltage	V _{GS(th)}	1.0	—	2.1	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance (Note 8)	R _{DS(on)}	—	25 36	30 40	mΩ	V _{GS} = 10V, I _D = 6A V _{GS} = 4.5V, I _D = 5A
Forward Transconductance (Note 8)	g _{FS}	—	5	—	S	V _{DS} = 10V, I _D = 8A
Diode Forward Voltage (Note 8)	V _{SD}	—	0.7	1.1	V	I _S = 2.25A, V _{GS} = 0V
DYNAMIC PARAMETERS (Note 9)						
Total Gate Charge	Q _g	—	10.5	—	nC	V _{GS} = 5V, V _{DS} = 15V, I _D = 6A
Gate-Source Charge	Q _{gs}	—	3.8	—	nC	V _{GS} = 10V, V _{DS} = 15V, I _D = 6A
Gate-Drain Charge	Q _{gd}	—	2.9	—	nC	V _{GS} = 10V, V _{DS} = 15V, I _D = 6A
Turn-On Delay Time	t _{D(on)}	—	11	—	ns	V _{DD} = 15V, V _{GS} = 10V, R _D = 1.8Ω, R _G = 6Ω
Turn-On Rise Time	t _r	—	7	—	ns	
Turn-Off Delay Time	t _{D(off)}	—	63	—	ns	
Turn-Off Fall Time	t _f	—	30	—	ns	
Input Capacitance	C _{iss}	—	755	—	pF	V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	136	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	108	—	pF	

Notes: 8. Test pulse width t = 300ms.
9. Guaranteed by design. Not subject to production testing.

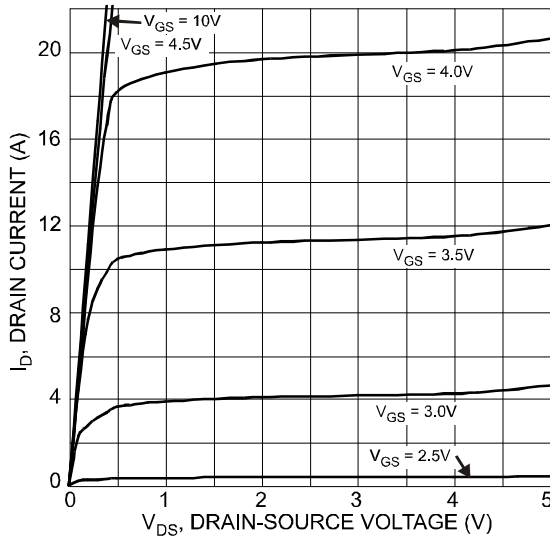


Fig. 1 Typical Output Characteristics

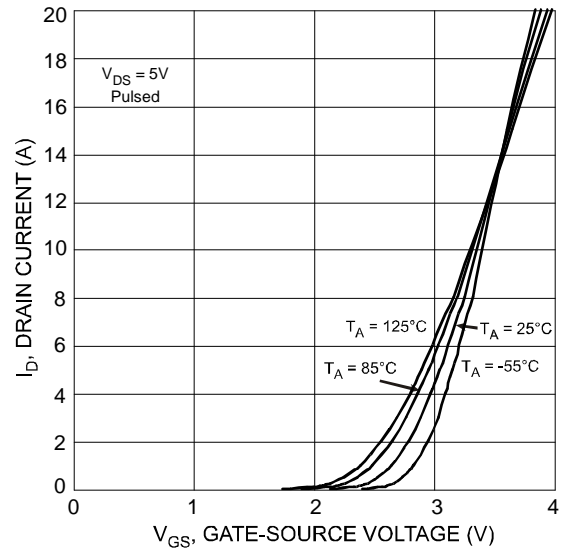


Fig. 2 Typical Transfer Characteristics

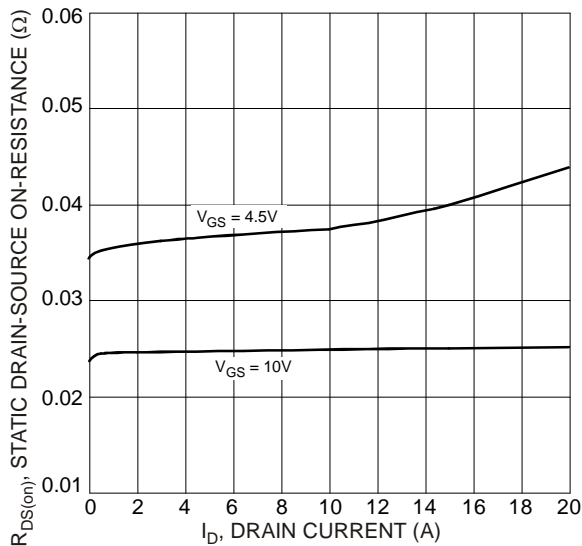


Fig. 3 On-Resistance vs. Drain Current and Gate Voltage

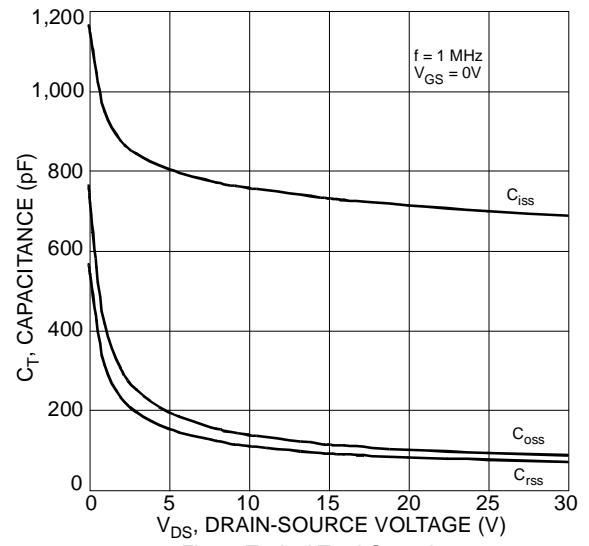


Fig. 4 Typical Total Capacitance

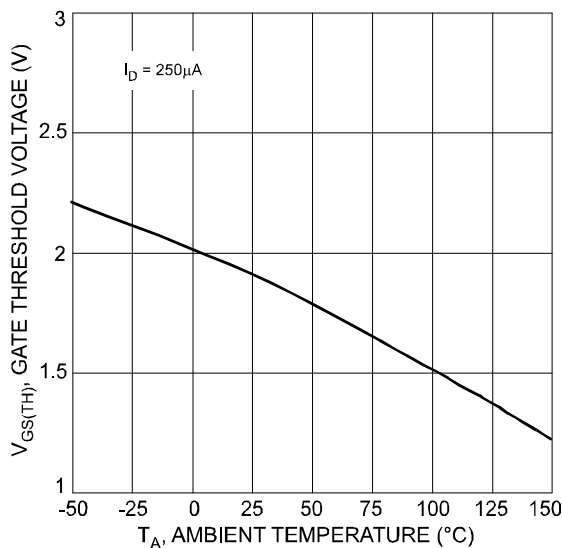


Fig. 5 Gate Threshold Voltage vs. Ambient Temperature

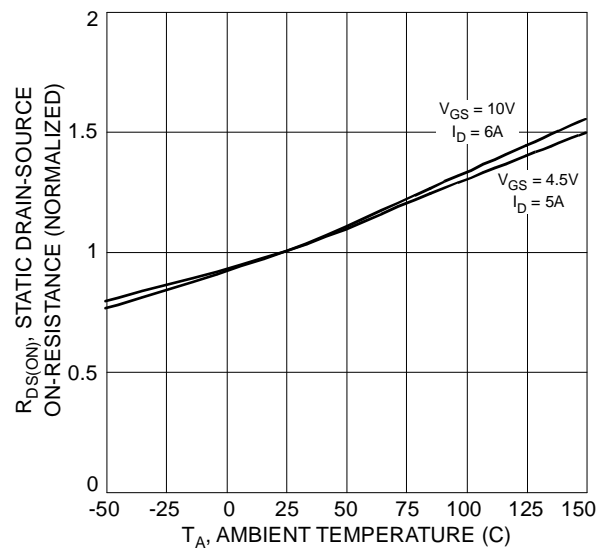


Fig. 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

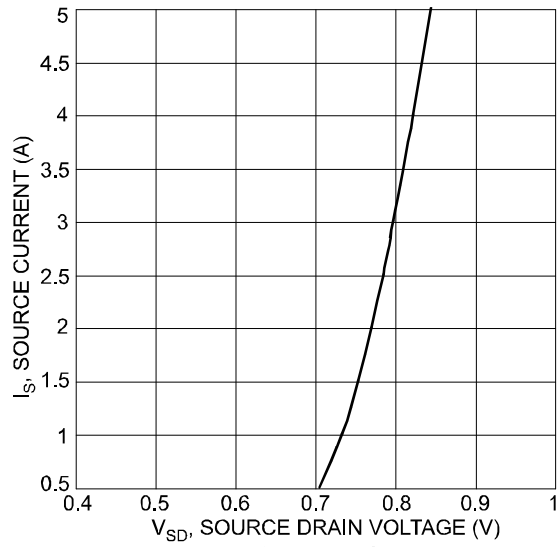
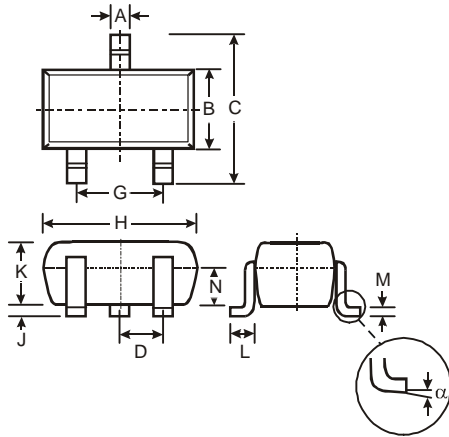


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

Package Outline Dimensions

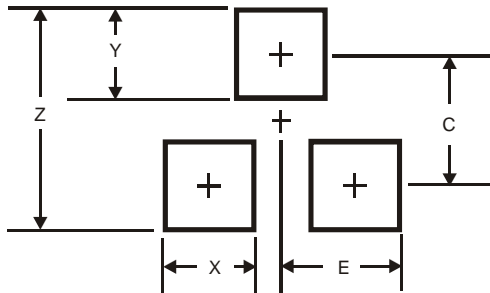
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SC-59			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	-	-	0.95
G	-	-	1.90
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	3.4
X	0.8
Y	1.0
C	2.4
E	1.35

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